NSN 5961-00-479-7900

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Inclosure Material: Metal **Overall Length:** 1.253 inches **End Application:** Aircraft; radar; fire control system; sonar acoustic miscellaneous; **Mounting Facility Quantity:** 1 **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 0.423 inches and 0.438 inches **Thread Size:** 0.190 inches **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 150.0 regulator voltage **Voltage Tolerance In Percent:** -5.0/+5.0 **Current Rating Per Characteristic:** 17.00 milliamperes source cutoff current horsepower metric and 62.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Weapon system essential **Precious Material And Location:** Terminal surface option gold **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 threaded stud and 1 tab, solder lug

Specification Data:

81349-mil-s-19500/124 government specification

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	Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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